

AMENDMENTS TO THE CLAIMS

Claim 1 (Currently Amended) An opto-electronic device with an integrated light deflector, comprising:

a passive optical waveguide having a lower cladding layer, a core, and an upper cladding layer to guide and transmit optical signals; and

a light deflector formed by patterning the upper cladding layer in a predetermined shape at an upper portion of the passive optical waveguide, the light deflector integrated with a laser diode,

wherein a refractive index of the core under the predetermined shape is modified to change a propagation direction of~~deflect~~ a light beam guided to the light deflector by the passive optical waveguide by applying a current or an electrical field to a particular portion of the light deflector having the predetermined shape, and the light deflector and the laser diode made of a same material.

Claim 2 (Original) The opto-electronic device with an integrated light deflector according to claim 1, wherein the predetermined shape is formed to make an angle of an emergent light beam different from that of an incident light beam.

Claim 3 (Original) The opto-electronic device with an integrated light deflector according to claim 2, wherein the predetermined shape is a triangle or a trapezoid.

Claim 4 (Original) The opto-electronic device with an integrated light deflector according to claim 1, wherein the light deflector is an array in which the predetermined shapes are repeatedly aligned, the array being an array having identical shapes, an array in which identical shapes have different incident angles or optical signals, or a combination thereof.

Claim 5 (Original) The opto-electronic device with an integrated light deflector according to claim 1, wherein the opto-electronic device comprises an active area for generating the optical signals.

Claim 6 (Original) The opto-electronic device with an integrated light deflector according to claim 5, wherein the cladding areas of the passive optical waveguide are composed of an InP material, and the core area and the active area are composed of an InGaAsP material.

Claim 7 (Original) The opto-electronic device with an integrated light deflector according to claim 1, wherein the predetermined shape is patterned by an embossing or engraving method.

Claim 8 (Currently Amended) An opto-electronic device with an integrated light deflector comprising:

a passive optical waveguide having a lower cladding layer, a core, and an upper cladding layer to guide and transmit optical signals; and

a light deflector having an electrode formed to have a predetermined shape by patterning an upper portion of the upper cladding layer of the passive optical waveguide, the light deflector integrated with a laser diode made of the same material as the light deflector,

wherein a reflective index of the core under the predetermined shape is modified to change a propagation direction of~~deflect~~ a light beam guided to the light deflector by the passive optical waveguide~~propagation~~ by applying a current or an electrical field to a particular portion of the light deflector having the predetermined shape.

Claim 9 (Original) The opto-electronic device with an integrated light deflector according to claim 8, wherein the predetermined shape is formed to make an angle of an emergent light beam different from that of an incident light beam.

Claim 10 (Original) The opto-electronic device with an integrated light deflector according to claim 9, wherein the predetermined shape is a triangle or a trapezoid.

Claim 11 (Original) The opto-electronic device with an integrated light deflector according to claim 8, wherein the light deflector is an array in which the predetermined

shapes are repeatedly aligned, the array being an array having identical shapes, an array in which identical shapes have different incident angles of optical signals, or a combination thereof.

Claim 12 (Original) The opto-electronic device with an integrated light deflector according to claim 8, wherein the opto-electronic device comprises an active area for generating the optical signals.

Claim 13 (Original) The opto-electronic device with an integrated light deflector according to claim 12, wherein the cladding areas of the passive optical waveguide are composed of an InP material, and the core area and the active area are composed of an InGaAsP material.

Claim 14 (Original) The opto-electronic device with an integrated light deflector according to claim 8, wherein the predetermined shape is patterned by an embossing or engraving method.

Claim 15 (Currently Amended) A wavelength tunable external cavity laser, comprising:

a light source with an integrated light deflector comprising a passive optical waveguide having a lower cladding layer, a core, and an upper cladding layer to guide and transmit optical signals, an active area for generating the optical signals, and the light deflector formed by patterning the upper cladding layer in a predetermined shape at an upper portion of a predetermined area of the passive optical waveguide, the light source and the integrated light deflector are made of a same material;

a collimator lens for collimating a light beam emergent from the light source; and
a diffraction grating for changing a diffraction angle depending on a wavelength of the light beam through the collimator lens,

wherein a propagation direction of the light beam guided to the deflector by the passive optical waveguide ~~propagation is changed~~ ~~is deflected~~ by modifying a refractive index of the core under the predetermined shape by applying a current or an electrical field to a particular portion of the light deflector having the predetermined shape.

Claim 16 (Original) The wavelength tunable external cavity laser according to claim 15, wherein the wavelength tunable external cavity laser further comprises a reflecting mirror for reflecting a specific wavelength diffracted by the diffraction grating.